ON Semiconductor

Is Now

Onsemi

To learn more about onsemi[™], please visit our website at <u>www.onsemi.com</u>

onsemi and ONSEMI. and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product factures, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and asfety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or by customer's technical experts. onsemi products and actal performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use onsemi products for any such unintended or unauthorized application, Buyer shall indemnify and hold onsemi and its officers, employees, subsidiari

Zero Voltage Switch

This series is designed for thyristor control in a variety of AC power switching applications for AC input voltages of 24 V, 120 V, 208/230 V, and 277 V @ 50/60 Hz.

Applications:

- Relay Control
- Valve Control
- Heater Control
- Lamp Control
- On–Off Motor Switching
- Differential Comparator with Self–Contained Power Supply for Industrial Applications
- Synchronous Switching of Flashing Lights



ON Semiconductor®

http://onsemi.com

ZERO VOLTAGE SWITCH

SEMICONDUCTOR TECHNICAL DATA

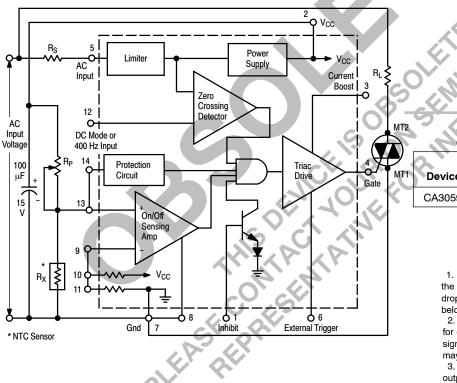


Figure 1. Representative Block Diagram

AC Input Voltage (50/60 Hz) Vac	Input Series Resistor (R _S) kΩ	Dissipation Rating for R _S w
24	2.0	0.5
120	10	2.0
208/230	20	4.0
277	25	5.0

ORDERING INFORMATION

PLASTIC PACKAGE

CASE 646

Device	Operating Temperature Range	Package
CA3059	$T_A = -40^\circ$ to $+85^\circ$ C	Plastic DIP

FUNCTIONAL BLOCK DESCRIPTION

1. Limiter-Power Supply — Allows operation of the CA3059 directly from an AC line. Suggested dropping resistor (R_S) values are given in the table below.

2. Differential On/Off Sensing Amplifier — Tests for condition of external sensors or input command signals. Proportional control capability or hysteresis may be implemented using this block.

3. Zero-Crossing Detector — Synchronizes the output pulses to the zero voltage point of the AC cycle. This synchronization eliminates RFI when used with resistive loads.

4. **Triac Drive** — Supplies high-current pulses to the external power controlling thyristor.

5. **Protection Circuit** — A built-in circuit may be actuated, if the sensor opens or shorts, to remove the drive current from the external triac.

6. **Inhibit Capability** — Thyristor firing may be inhibited by the action of an internal diode gate at Pin 1.

7. **High Power DC Comparator Operation** — Operation in this mode is accomplished by connecting Pin 7 to Pin 12 (thus overriding the action of the zero-crossing detector). When Pin 13 is positive with respect to Pin 9, current to the thyristor is continuous.

MAXIMUM RATINGS

Rating		Symbol	Value	Unit
DC Supply Voltage		V _{CC}		Vdc
(Between Pins 2 and 7)			12	
DC Supply Voltage		V _{CC}		Vdc
(Between Pins 2 and 8)			12	
Peak Supply Current (Pins 5 and 7)		I _{5,7}	±[50	mA
Fail-Safe Input Current (Pin 14)		I ₁₄	2.0	mA
Output Pulse Current (Pin 4) (Note 1)		l _{out}	150	mA
Junction Temperature		TJ	150	°C
Operating Temperature Range		T _A	– 40 to + 85	°C
Storage Temperature Range		T _{stg}	– 65 to + 150	°C

ELECTRICAL CHARACTERISTICS (Operation @ 120 Vrms, 50-60 Hz, T_A = 25°C [Note 2])

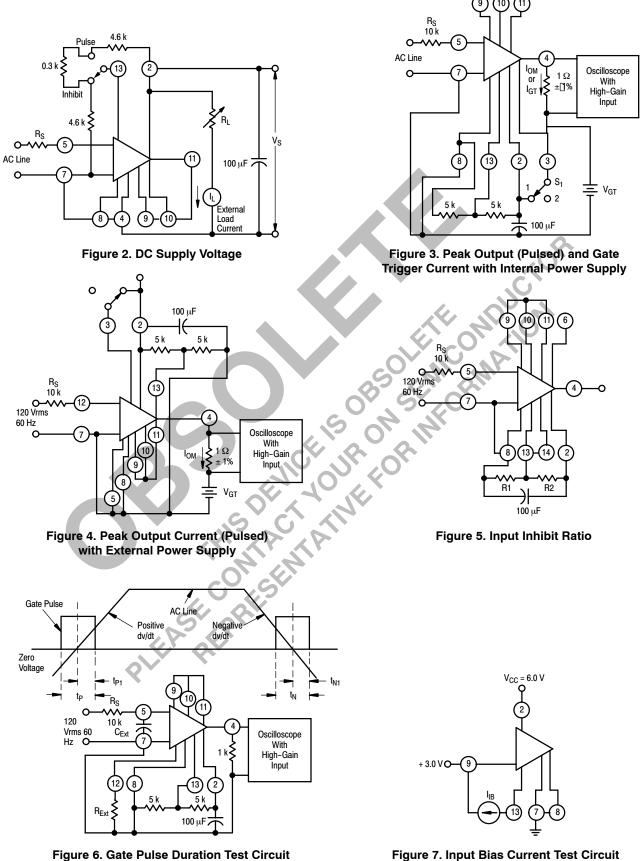
Characteristic	Figure	Symbol	Min	Тур	Max	Unit
DC Supply Voltage Inhibit Mode R _S = 10 k, I _L = 0	2	Vs	6.1	6.5	7.0	Vdc
$R_{S} = 5.0 \text{ k}, \text{ I}_{L} = 2.0 \text{ mA}$ Pulse Mode			5	6.1	/ –	
R _S = 10 k, I _L = 0 R _S = 5.0 k, R _L = 2.0 mA		- F	6.0	6.4 6.2	7.0	
Gate Trigger Current (V _{GT} = 1.0 V, Pins 3 and 2 connected)	3	IGT		160	—	mA
Peak Output Current, Pulsed With Internal Power Supply, V _{GT} = 0	3	Іом	KO.			mA
Pin 3 Open Pins 3 and 2 Connected	CH P	0, 41	50 90	125 190	_	
With External Power Supply, V _{CC} = 12 V, V _{GT} = 0 Pin 3 Open Pins 3 and 2 Connected		KO.		230 300		
Inhibit Input Ratio (Ratio of Voltage @ Pin 9 to Pin 2)	5	V ₉ /V ₂	0.465	0.485	0.520	
Total Gate Pulse Duration (C _{Ext} = 0) Positive dv/dt	6	tp	70	100	140	μs
Negative dv/dt		τ _n	70	100	140	
Pulse Duration After Zero Crossing ($C_{Ext} = 0, R_{Ext} = \infty$)	6					μs
Positive dv/dt Negative dv/dt		t _{p1} t _{n1}		50 60	_	
Output Leakage Current Inhibit Mode (Note 3)	3	I ₄		0.001	10	μA
nput Bias Current	7	I _{IB}		0.15	1.0	μA
Common Mode Input Voltage Range (Pins 9 and 13 Connected)	_	V _{CMR}		1.4 to 5.0	—	Vdc
Inhibit Input Voltage	8	V ₁		1.4	1.6	Vdc
External Trigger Voltage		V ₆ -V ₄		1.4	_	Vdc

NOTES: 1. Care must be taken, especially when using an external power supply, that total package dissipation is not exceeded.

2. The values given in the Electrical Characteristics Table at 120 V also apply for operation at input voltages of 24 V, 208/230 V, and 277 V, except for Pulse Duration test. However, the series resistor (R_S) must have the indicated value, shown in Table A for the specified input voltage. 3. I₄ out of Pin 4, 2.0 V on Pin 1, S₁ position 2.

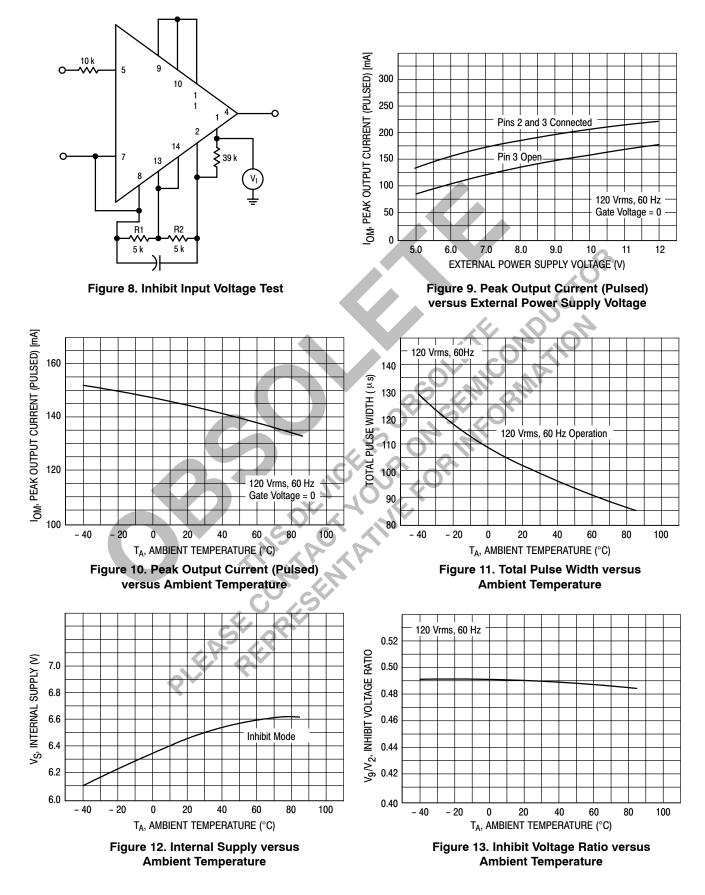
TEST CIRCUITS

(All resistor values are in ohms)



with Associated Waveform

TYPICAL CHARACTERISTICS



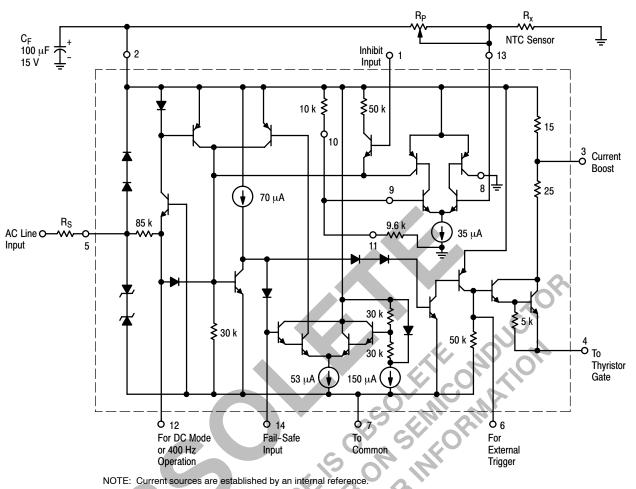


Figure 14. Circuit Schematic

APPLICATION INFORMATION

Power Supply

The CA3059 is a self-powered circuit, powered from the AC line through an appropriate dropping resistor (see Table A). The internal supply is designed to power the auxiliary power circuits.

In applications where more output current from the internal supply is required, an external power supply of higher voltage should be used. To use an external power supply, connect Pin 5 and Pin 7 together and apply the synchronizing voltage to Pin 12 and the DC supply voltage to Pin 2 as shown in Figure 4.

Operation of Protection Circuit

The protection circuit, when connected, will remove current drive from the triac if an open or shorted sensor is detected. This circuit is activated by connecting Pin 13 to Pin 14 (see Figure 1).

The following conditions should be observed when the protection circuit is utilized:

a. The internal supply should be used and the external load current must be limited to 2 mA with a 5 k Ω dropping resistor.

- b. Sensor Resistance (R_X) and R_P values should be between 2 k Ω and 100 k Ω .
- c. The relationship $0.33 < R_X/R_P < 3$ must be met over the anticipated temperature range to prevent undesired activation of the circuit. A shunt or series resistor may have to be added.

External Inhibit Function

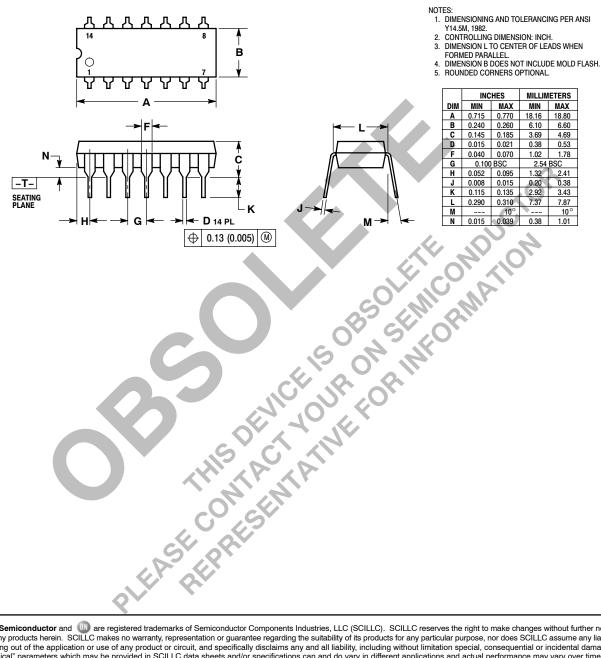
A priority inhibit command applied to Pin 1 will remove current drive from the thyristor. A command of at least +1.2 V @ 10 μ A is required. A DTL or TTL logic 1 applied to Pin 1 will activate the inhibit function.

DC Gate Current Mode

When comparator operation is desired or inductive loads are being switched, Pins 7 and 12 should be connected. This connection disables the zero-crossing detector to permit the flow of gate current from the differential sensing amplifier on demand. Care should be exercised to avoid possible overloading of the internal power supply when operating the device in this mode. A resistor should be inserted between Pin 4 and the thyristor gate in order to limit the current.

PACKAGE DIMENSIONS

PLASTIC PACKAGE CASE 646–06 ISSUE M



ON Semiconductor and IIII are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typical" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other application in which the failure of the SCILLC product customer application. By customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products for any sother application in which the failure of the SCILLC product customer application in which the failure of the SCILLC product customer application in which the failure of the SCILLC product customer application is a subject to customer application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death applicatio experiment. SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada Fax: 303–675–2176 or 800–344–3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support:

Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81–3–5773–3850 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative